

Ultrafast Rectifier

30 A, 600 V

RURG3060CC-F085

Description

The RURG3060-F085 is an dual ultrafast diode with soft recovery characteristics ($t_{rr} < 80$ ns). It has low forward voltage drop and is silicon nitride passivated ionimplanted epitaxial planar construction.

This device is intended for use as a freewheeling/clamping diode and rectifier in a variety of switching power supplies and other power switching applications. Its low stored charge and ultrafast recovery with soft recovery characteristic minimizes ringing and electrical noise in many power switching circuits, thus reducing power loss in the switching transistors.

Features

- High Speed Switching ($t_{rr} = 60$ ns (Typ.) @ $I_F = 30$ A)
- Low Forward Voltage ($V_F = 1.5$ V (Max) @ $I_F = 30$ A)
- Avalanche Energy Rated
- AEC-Q101 Qualified and PPAP Capable
- This is a Pb-Free Device

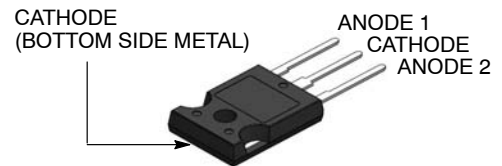
Applications

- Automotive DC/DC Converter
- Automotive On Board Charger
- Switching Power Supply
- Power Switching Circuits

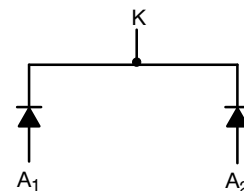


ON Semiconductor®

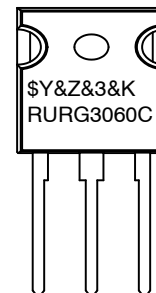
www.onsemi.com



TO-247-3LD
CASE 340CK



MARKING DIAGRAM



\$Y	= ON Semiconductor Logo
&Z	= Assembly Plant Code
&3	= Numeric Date Code
&K	= Lot Code
RURG3060C	= Specific Device Code

ORDERING INFORMATION

See detailed ordering and shipping information on page 2 of this data sheet.

RURG3060CC-F085

ABSOLUTE MAXIMUM RATINGS (T_C = 25°C unless otherwise noted)

Parameter	Symbol	Ratings	Unit
Peak Repetitive Reverse Voltage	V _{RRM}	600	V
Working Peak Reverse Voltage	V _{RWM}	600	V
DC Blocking Voltage	V _R	600	V
Average Rectified Forward Current (T _C = 25°C)	I _{F(AV)}	30	A
Non-repetitive Peak Surge Current (Halfwave 1 Phase 50 Hz)	I _{FSM}	90	A
Avalanche Energy (1 A, 40 mH)	E _{AVL}	20	mJ
Operating Junction and Storage Temperature	T _J , T _{STG}	-55 to +175	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

PACKAGE MARKING AND ORDERING INFORMATION

Device	Device Marking	Package	Tube	Quantity
RURG3060CC-F085	RURG3060C	TO-247	-	30

THERMAL CHARACTERISTICS (T_C = 25°C unless otherwise noted)

Parameter	Symbol	Max	Unit
Maximum Thermal Resistance, Junction to Case (Single Anode)	R _{θJC}	1	°C/W
Maximum Thermal Resistance, Junction to Ambient	R _{θJA}	45	°C/W

ELECTRICAL CHARACTERISTICS (T_C = 25°C unless otherwise noted)

Parameter	Symbol	Conditions	Min	Typ	Max	Unit	
Instantaneous Reverse Current	I _R	V _R = 600 V	T _C = 25°C	-	-	250	μA
			T _C = 175°C	-	-	1.0	mA
Instantaneous Forward Voltage	V _{FM} (Note 1)	I _F = 30 A	T _C = 25°C	-	1.26	1.5	V
			T _C = 175°C	-	1.06	1.3	V
Reverse Recovery Time	t _{rr} (Note 2)	I _F = 1 A, di/dt = 100 A/μs, V _{CC} = 390 V	T _C = 25°C	-	35	55	ns
			T _C = 25°C	-	60	80	ns
			T _C = 175°C	-	231	-	ns
Reverse Recovery Time	t _a	I _F = 30 A, di/dt = 100 A/μs, V _{CC} = 390 V	T _C = 25°C	-	31	-	ns
	t _b			-	29	-	ns
Reverse Recovery Charge	Q _{rr}			-	92	-	nC
Avalanche Energy	E _{AVL}	I _{AV} = 1.0 A, L = 40 mH		20	-	-	mJ

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

1. Test Pulse Width = 300 μs, Duty Cycle = 3%
2. Guaranteed by design.

TEST CIRCUIT AND WAVEFORMS

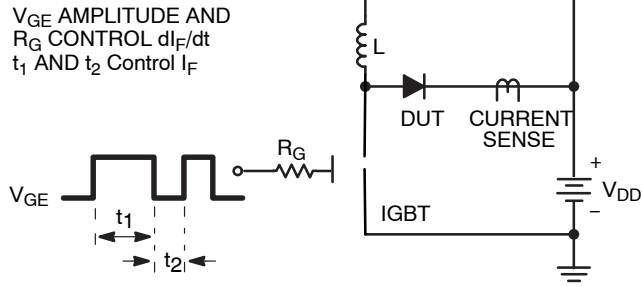


Figure 1. t_{rr} Test Circuit

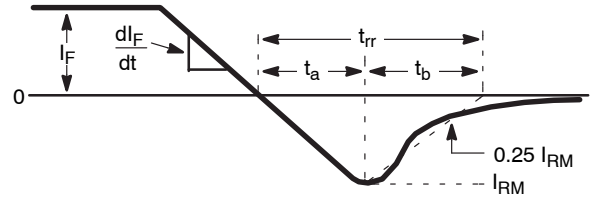


Figure 2. t_{rr} Waveforms and Definitions

$I_{MAX} = 1 \text{ A}$
 $L = 40 \text{ mH}$
 $R < 0.1 \Omega$
 $E_{AVL} = 1/2 L I^2 [V_{R(AVL)} / (V_{R(AVL)} - V_{DD})]$
 $Q_1 = \text{IGBT (} BV_{CES} > \text{DUT } V_{R(AVL)} \text{)}$

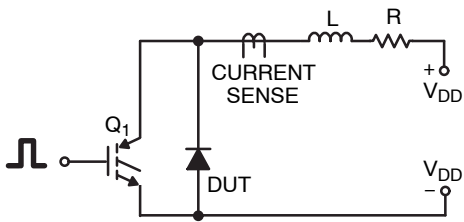


Figure 3. Avalanche Energy Test Circuit

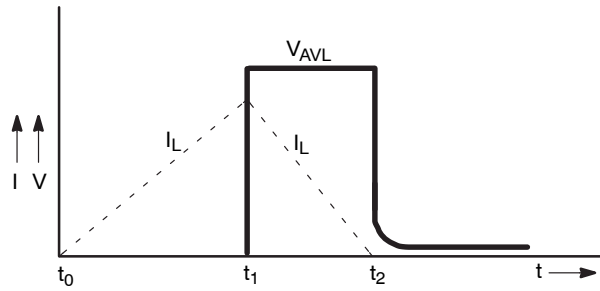


Figure 4. Avalanche Current and Voltage Waveforms

TYPICAL PERFORMANCE CHARACTERISTICS (Single Anode)

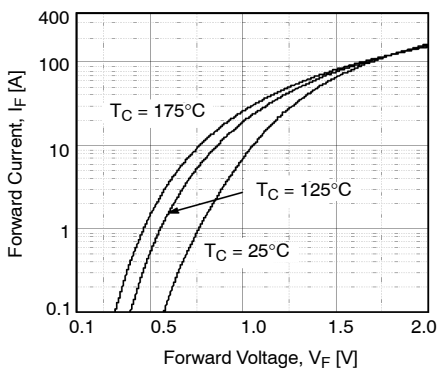


Figure 5. Typical Forward Voltage Drop vs. Forward Current

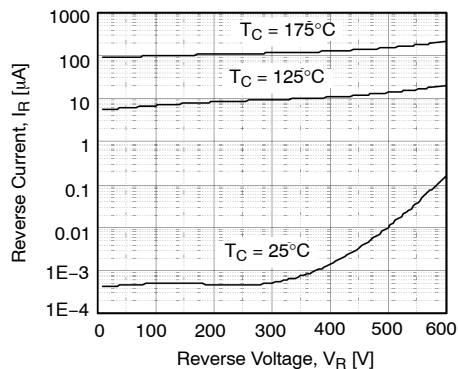


Figure 6. Typical Reverse Current vs. Reverse Voltage

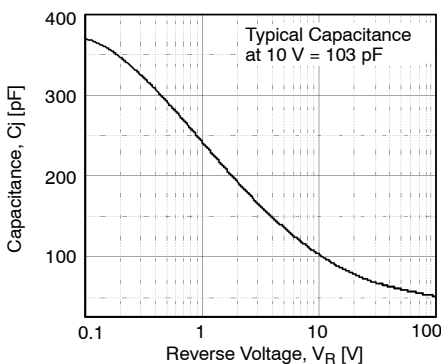


Figure 7. Typical Junction Capacitance

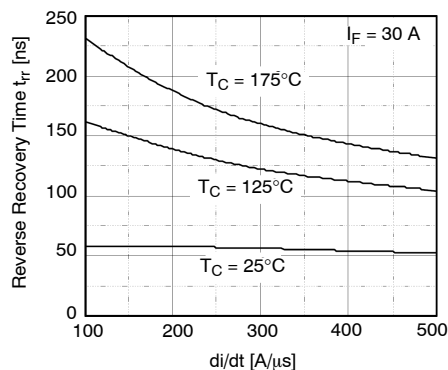


Figure 8. Typical Reverse Recovery Time vs. di/dt

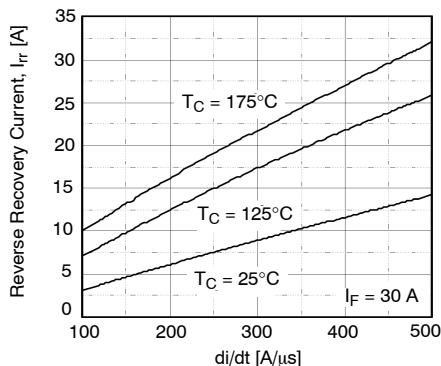


Figure 9. Typical Reverse Recovery Current vs. di/dt

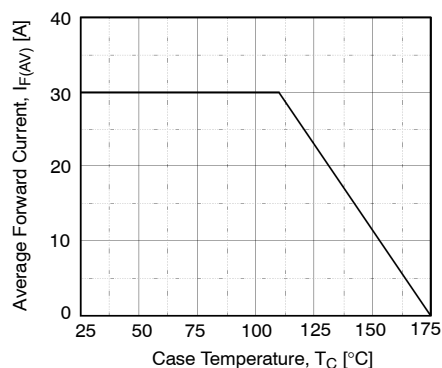


Figure 10. Forward Current Derating Curve

TYPICAL PERFORMANCE CHARACTERISTICS (continued)

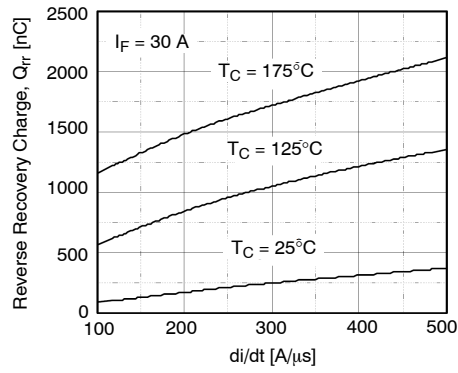


Figure 11. Reverse Recovery Charge

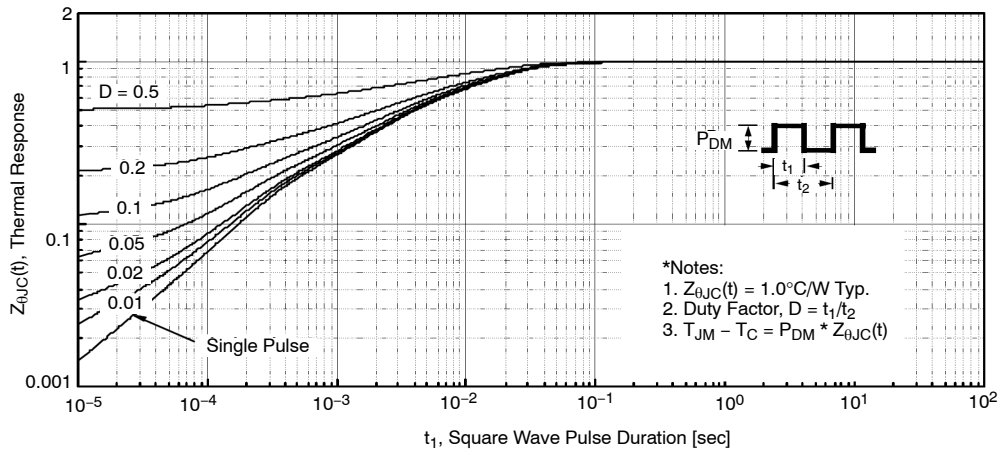
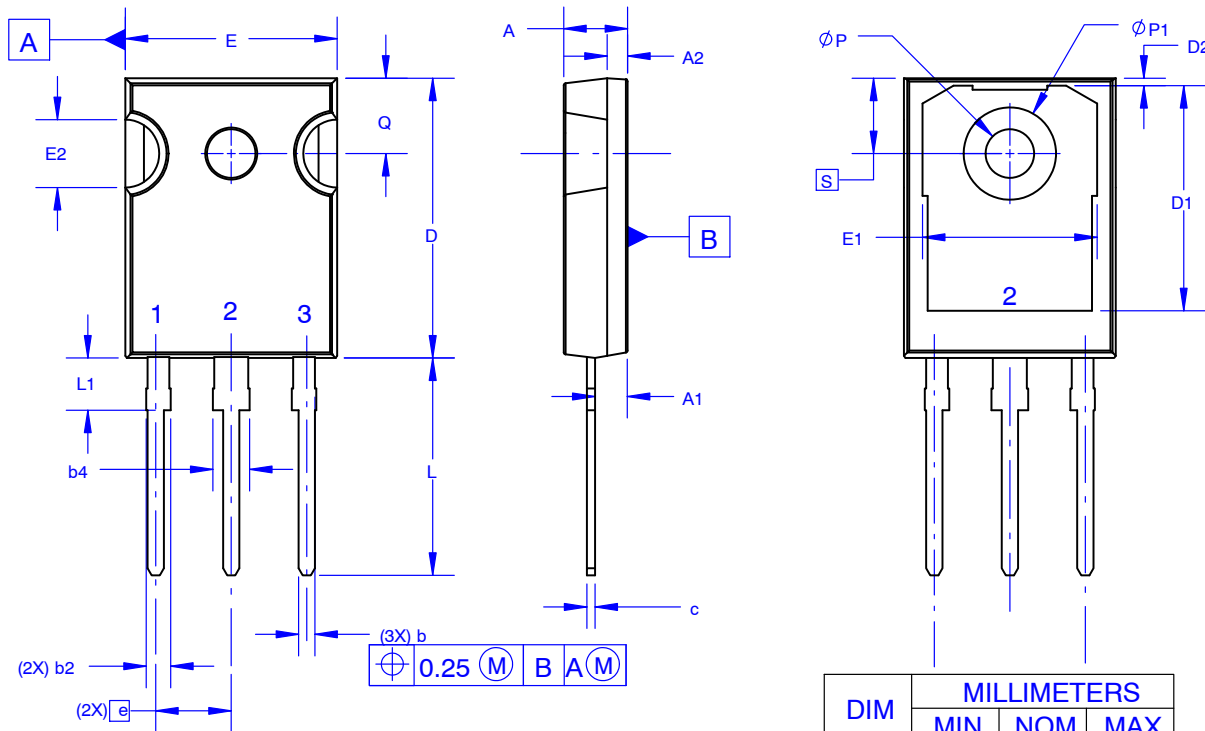


Figure 12. Transient Thermal Response Curve



TO-247-3LD SHORT LEAD
CASE 340CK
ISSUE A

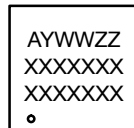
DATE 31 JAN 2019



NOTES: UNLESS OTHERWISE SPECIFIED.

- A. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.
- B. ALL DIMENSIONS ARE IN MILLIMETERS.
- C. DRAWING CONFORMS TO ASME Y14.5 - 2009.
- D. DIMENSION A1 TO BE MEASURED IN THE REGION DEFINED BY L1.
- E. LEAD FINISH IS UNCONTROLLED IN THE REGION DEFINED BY L1.

GENERIC MARKING DIAGRAM*



- XXXX = Specific Device Code
- A = Assembly Location
- Y = Year
- WW = Work Week
- ZZ = Assembly Lot Code

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

DIM	MILLIMETERS		
	MIN	NOM	MAX
A	4.58	4.70	4.82
A1	2.20	2.40	2.60
A2	1.40	1.50	1.60
b	1.17	1.26	1.35
b2	1.53	1.65	1.77
b4	2.42	2.54	2.66
c	0.51	0.61	0.71
D	20.32	20.57	20.82
D1	13.08	~	~
D2	0.51	0.93	1.35
E	15.37	15.62	15.87
E1	12.81	~	~
E2	4.96	5.08	5.20
e	~	5.56	~
L	15.75	16.00	16.25
L1	3.69	3.81	3.93
ØP	3.51	3.58	3.65
ØP1	6.60	6.80	7.00
Q	5.34	5.46	5.58
S	5.34	5.46	5.58

DOCUMENT NUMBER:	98AON13851G	Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.
DESCRIPTION:	TO-247-3LD SHORT LEAD	PAGE 1 OF 1

ON Semiconductor and are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. ON Semiconductor does not convey any license under its patent rights nor the rights of others.

onsemi, **Onsemi**, and other names, marks, and brands are registered and/or common law trademarks of Semiconductor Components Industries, LLC dba "**onsemi**" or its affiliates and/or subsidiaries in the United States and/or other countries. **onsemi** owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of **onsemi**'s product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. **onsemi** reserves the right to make changes at any time to any products or information herein, without notice. The information herein is provided "as-is" and **onsemi** makes no warranty, representation or guarantee regarding the accuracy of the information, product features, availability, functionality, or suitability of its products for any particular purpose, nor does **onsemi** assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using **onsemi** products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by **onsemi**. "Typical" parameters which may be provided in **onsemi** data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. **onsemi** does not convey any license under any of its intellectual property rights nor the rights of others. **onsemi** products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use **onsemi** products for any such unintended or unauthorized application, Buyer shall indemnify and hold **onsemi** and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that **onsemi** was negligent regarding the design or manufacture of the part. **onsemi** is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:

Email Requests to: orderlit@onsemi.com

onsemi Website: www.onsemi.com

TECHNICAL SUPPORT

North American Technical Support:

Voice Mail: 1 800-282-9855 Toll Free USA/Canada

Phone: 011 421 33 790 2910

Europe, Middle East and Africa Technical Support:

Phone: 00421 33 790 2910

For additional information, please contact your local Sales Representative

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for [Rectifiers](#) category:

Click to view products by [ON Semiconductor](#) manufacturer:

Other Similar products are found below :

[70HFR40](#) [RL252-TP](#) [150KR30A](#) [1N5397](#) [NTE5841](#) [NTE6038](#) [SCF5000](#) [1N4002G](#) [1N4005-TR](#) [JANS1N6640US](#) [481235F](#)
[RRE02VS6SGTR](#) [067907F](#) [MS306](#) [70HF40](#) [T85HFL60S02](#) [US2JFL-TP](#) [A1N5404G-G](#) [CRS04\(T5L,TEMQ\)](#) [ACGRA4007-HF](#)
[ACGRB207-HF](#) [CLH03\(TE16L,Q\)](#) [ACGRC307-HF](#) [ACEFC304-HF](#) [NTE6356](#) [NTE6359](#) [NTE6002](#) [NTE6023](#) [NTE6039](#) [NTE6077](#)
[85HFR60](#) [40HFR60](#) [70HF120](#) [85HFR80](#) [D126A45C](#) [SCF7500](#) [D251N08B](#) [SCHJ22.5K](#) [SM100](#) [SCPA2](#) [SCH10000](#) [SDHD5K](#) [VS-](#)
[12FL100S10](#) [ACGRA4001-HF](#) [D1821SH45T PR](#) [D1251S45T](#) [NTE5990](#) [NTE6358](#) [NTE6162](#) [NTE5850](#)